

Basic review questions

Submit on or before 14-11-19

- 1 What is an intrinsic semiconductor? Explain its crystal structure.
- 2 What is hole current? Explain with crystal structure how hole current exists?
- 3 What is thermal generation?
- 4 Why intrinsic semiconductors are not used in practical application?
- 5 Explain the formation of n-type semiconductor.
- 6 Explain the behavior of forward biased diode
- 7 Explain the behavior of a reverse biased diode.
- 8 What is a transistor? Explain its transfer of resistance application.
- 9 Explain the various components of the transistors.
- 10 What is reverse saturation current?
- 11 What is I_{CB} ? Why it is greater than I_{CO} ?
- 12 What is CB configuration? Explain the *input* and *output* configuration.
- 13 What is CE configuration? Explain the *input* and *output* configuration.
- 14 What are the different types of transistor configurations?
- 15 Explain the required condition for the transistor to be in saturation region.
- 16 Why CE configuration is widely used in amplifier circuits.
- 17 In CB configuration $\alpha=0.98$, a voltage drop of 4.9V is obtained across 5KW when connected in the collector circuit. Find the base current.
- 18 The emitter current I_E in a transistor is 3mA. If the leakage current I_{CBO} is 5 μ A and $\alpha=0.95$. Calculate the collector and base current.
- 19 For a common base emitter circuit $I_E=1$ mA and $I_B=0.044$ mA. Calculate α , β and I_C .
- 20 Obtain the relation between α , β and γ
21. What do you mean by Q-point of a transistor? What is its significance?
22. Explain the concepts of ac and dc load lines.
23. Compare CE, CB and CC configurations.
- 24 Which configuration of Bipolar Transistor is called as Emitter follower & why, for That purpose is it used?
- 25 A CE connected amplifier has $C_{cb}= 5$ pF, $C_{be}=12$ pF, $h_{fe}= 100$, $h_{ie}= 1.5$ k Ω . Find the input capacitance to the circuit for a circuit collector resistance of 12k Ω .
- 26 Explain how device Capacitances plays dominant role in CE Amplifier in high frequency region.
- 27 Why transistor is called current controlled device?
- 28 Discuss the need for biasing the transistor.
- 29 What are 'emitter injection efficiently' and 'base transport factor' and how do they influence the transistor operation?
- 30 Which of the transistor currents is always the largest? Which is always the smallest? Which two currents are relatively close in magnitude?
- 31 Why silicon type transistors are more often used than germanium type?
- 32 Why is there a maximum limit of collector supply voltage for a transistor?
- 33 Explain why $I_{CEO} \gg I_{CBO}$?
- 34 Why CC configuration is called a voltage buffer? What is other name?
- 35 What are the main purposes for which a CC amplifier may be used.
- 36 What do you understand by collector reverse saturation? In which configuration does it have a greater value?
- 37 What is the need of power amplifier?
- 38 What is the difference between voltage amplifier and power amplifier?
- 39 Write the principle of class C push pull amplifier.
- 40 Explain driver stage and output stage in power amplifiers.